

Application Data Sheet**Application Information**

Application Type::	Regular
Subject Matter::	Utility
Title::	Trench MOSFET Having Implanted Drain-Drift Region And Process For Manufacturing The Same
Attorney Docket Number::	SCX010-5D US
Request for Early Publication?::	No
Request for Non-Publication?::	No
Total Drawing Sheets::	18
Small Entity?::	No
Petition Included?::	No
Secrecy Order in Parent Appl.?::	No

Applicant Information

Applicant Authority Type::	Inventor
Primary Citizenship Country::	US
Status::	Full Capacity
Given Name::	Mohamed
Middle Name::	N.
Family Name::	Darwish
Name Suffix::	
City of Residence::	Campbell
State or Province of Residence::	California
Country of Residence::	US
Street of Mailing Address::	675 Regas Drive
City of Mailing Address::	Campbell
State or Province of Mailing Address::	California
Country of Mailing Address::	US
Postal or Zip Code of mailing	95008

address::

Correspondence Information

Correspondence Customer Number:: 34036

Representative Information

Representative Customer Number::	34036
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Domestic Priority Information

Application::	Continuity Type::	Parent Application::	Parent Filing Date::
This application	Divisional of	10/317,568	12/12/02
10/317,568	Continuation in part of	09/898,652	07/03/01

Assignee Information

Assignee Name:: Siliconix incorporated
Street of Mailing Address:: 2201 Laurelwood Road
City of Mailing Address:: Santa Clara
State of Mailing Address:: California
Country of Mailing Address:: USA
Zip Code of Mailing Address:: 95054